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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

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November 2014

KSC945 NPN Epitaxial Silicon Transistor

Features

- Audio Frequency Amplifier and High-Frequency OSC.
- Complimentary to KSA733
- Collector-Base Voltage: V_{CBO} = 60 V
- High Current Gain Bandwidth Product: f_T = 300 MHz (Tyical)
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



1. Emitter 2. Base 3. Collector

Ordering Information

Part Number	Top Mark	Package	Packing Method	
KSC945YBU	C945	TO-92 3L	Bulk	
KSC945YTA	C945	TO-92 3L	Ammo	
KSC945GTA	C945	TO-92 3L	Ammo	
KSC945CYTA	C945	TO-92 3L	Ammo	
KSC945CGBU	C945	TO-92 3L	Bulk	
KSC945CGTA	C945	TO-92 3L	Ammo	

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	60	V
V _{CEO}	Collector-Emitter Voltage	50	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	150	mA
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to 150	°C

Thermal Characteristics(1)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
D	Power Dissipation	250	mW
P_{D}	Derate Above 25°C	2.0	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	500	°C/W

Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu\text{A}, I_E = 0$	60			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, I_B = 0$	50			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5			V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 40 \text{ V}, I_{E} = 0$			0.1	μΑ
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 3 \text{ V}, I_{C} = 0$			0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = 6 \text{ V}, I_{C} = 1.0 \text{ mA}$	40		700	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$		0.15	0.30	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 6 \text{ V, } I_{C} = 10 \text{ mA}$		300		MHz
C _{ob}	Output Capacitance	$V_{CB} = 6 \text{ V}, I_{E} = 0,$ f = 1 MHz		2.5		pF
NF	Noise Figure	$\begin{split} &V_{\text{CE}} = 6 \text{ V, } I_{\text{C}} = 0.5 \text{ mA,} \\ &f = 1 \text{ kHz, } R_{\text{S}} = 500 \Omega \end{split}$		4.0		dB

h_{FE} Classification

Classification	R	0	Υ	G	L
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240	200 ~ 400	350 ~ 700

Typical Performance Characteristics

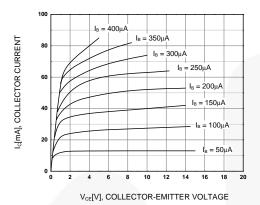


Figure 1. Static Characteristic

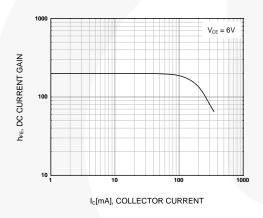


Figure 3. DC Current Gain

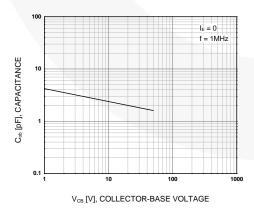


Figure 5. Output Capacitance

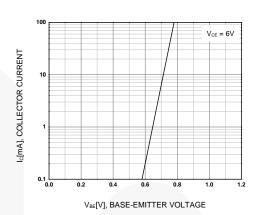


Figure 2. Transfer Characteristic

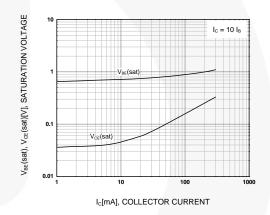


Figure 4. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

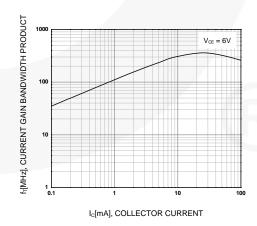
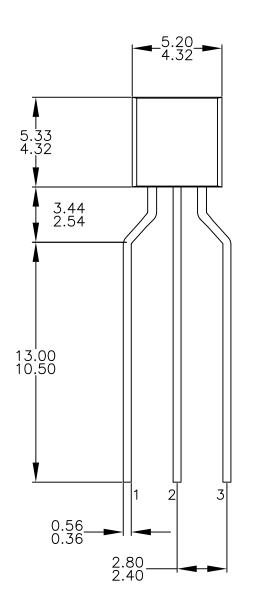
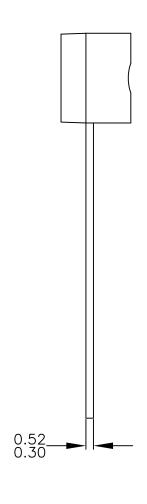
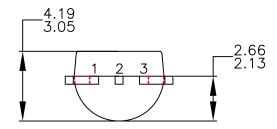


Figure 6. Current Gain Bandwidth Product

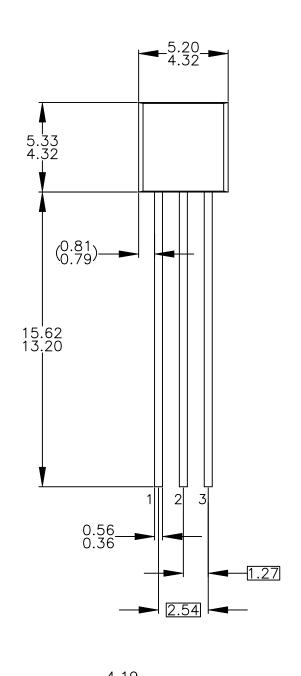


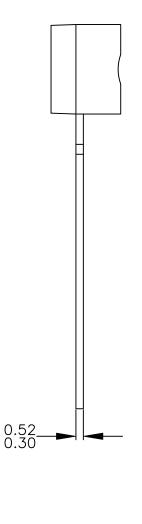




NOTES: UNLESS OTHERWISE SPECIFIED

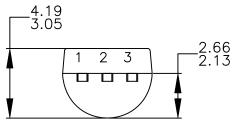
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 ALL DIMENSIONS ARE IN MILLIMETERS.
 DRAWING CONFORMS TO ASME Y14.5M-2009.
 DRAWING FILENAME: MKT-ZAO3FREV3.
 FAIRCHILD SEMICONDUCTOR.
- B. C. D. E.





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 DRAWING FILENAME: MKT-ZAO3DREV4.





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